## 1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a leadless ultra small DSN1006-2 (SOD993) Surface-Mounted Device (SMD) package.

### 2. Features and benefits

Average forward current: I<sub>F(AV)</sub> ≤ 1 A

Reverse voltage: V<sub>R</sub> ≤ 40 V

Low forward voltage, typical:  $V_F = 435 \text{ mV}$ Low reverse current, typical:  $I_R = 325 \mu A$ 

Package height typ. 270 μm

### 3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications
- Ultra high-speed switching
- · LED backlight for mobile application

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; f = 20 kHz; $T_{sp} \le$ 145 °C; square wave	-	-	1	А
$V_R$	reverse voltage	T <sub>j</sub> = 25 °C	-	-	40	V
V <sub>F</sub>	forward voltage	$I_F = 1 \text{ A}; t_p \le 300  \mu\text{s}; \delta \le 0.02 ;$ $T_j = 25 ^{\circ}\text{C}$	-	435	505	mV
I <sub>R</sub>	reverse current	$V_R = 20 \text{ V; } t_p \le 3 \text{ ms; } \delta \le 0.3 \text{ ;}$ $T_j = 25 \text{ °C}$	-	30	115	μΑ
		$V_R = 40 \text{ V; } t_p \le 3 \text{ ms; } \delta \le 0.3 \text{ ;}$ $T_j = 25 \text{ °C}$	-	325	1250	μΑ





# **Pinning information**

Table 2. **Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		1 - 2
2	A	anode	1 2	sym001
			Transparent top view  DSN1006-2 (SOD993)	

<sup>[1]</sup> The marking bar indicates the cathode.

# **Ordering information**

Table 3. **Ordering information** 

Type number	Package				
	Name	Description	Version		
PMEG4010AESB	DSN1006-2	DSN1006-2, leadless ultra small package; 2 terminals; body 1.0 x 0.6 x 0.27 mm	SOD993		

## **Marking**

**Marking codes** Table 4.

Type number	Marking code
PMEG4010AESB	4A

### 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_R$	reverse voltage	T <sub>j</sub> = 25 °C		-	40	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 140 °C; δ = 1		-	1.4	Α
I <sub>F(AV)</sub>	average forward current	$\bar{\delta}$ = 0.5 ; f = 20 kHz; $T_{amb} \leq$ 115 °C; square wave	[1]	-	1	A
		$\delta$ = 0.5 ; f = 20 kHz; $T_{sp} \le$ 145 °C; square wave		-	1	A
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ ms}; \delta \le 0.25$		-	4	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	10	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	0.525	W
			[3]	-	1	W
			[1]	-	1.78	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm<sup>2</sup> each.

### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient		in free air	[1][2]	-	-	240	K/W
		[1][3]	-	-	125	K/W	
	ambient		[1][4]	-	-	70	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[5]	-	-	15	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm<sup>2</sup> each.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [5] Soldering point of anode tab.

PMEG4010AESB

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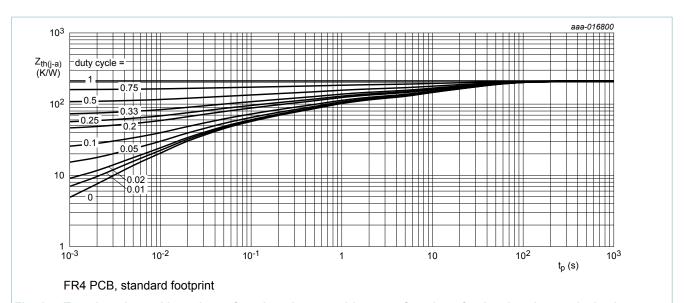
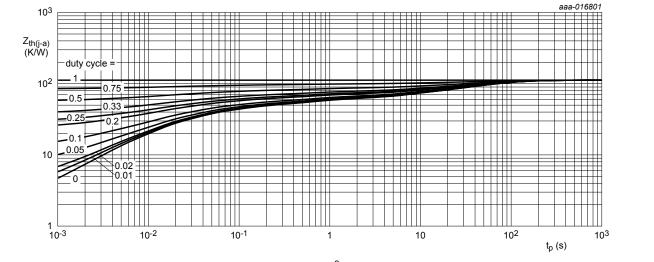


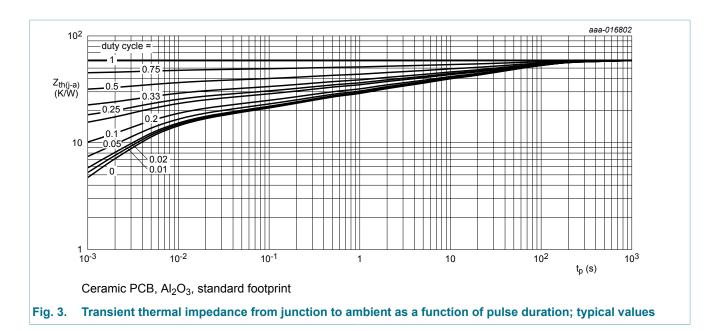
Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for anode and cathode 1 cm<sup>2</sup> each

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

**Product data sheet** 



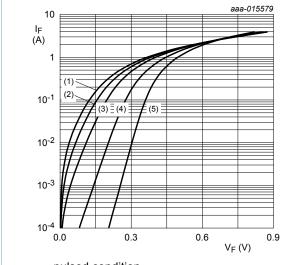
### 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)R}$	reverse breakdown voltage	$I_R = 10 \text{ mA}; t_p = 300  \mu\text{s}; \delta = 0.02 ;$ $T_j = 25 ^{\circ}\text{C}$	40	-	-	V
V <sub>F</sub> forward voltage	forward voltage	$I_F$ = 1 mA; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	145	-	mV
		$I_F$ = 10 mA; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_j$ = 25 °C	-	205	-	mV
	$I_F = 100 \text{ mA; } t_p \le 300  \mu \text{s; } \delta \le 0.02 \text{ ; }$ $T_j = 25 \text{ °C}$ $I_F = 200 \text{ mA; } t_p \le 300  \mu \text{s; } \delta \le 0.02 \text{ ; }$ $T_j = 25 \text{ °C}$	· ·	-	275	330	mV
		·	-	305	-	mV
		$I_F = 500 \text{ mA}; t_p \le 300  \mu\text{s}; \delta \le 0.02 ;$ $T_j = 25 ^{\circ}\text{C}$	-	365	425	mV
		$I_F$ = 700 mA; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_j$ = 25 °C	-	395	-	mV
		$I_F$ = 1 A; $t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_j$ = 25 °C	-	435	505	mV
I <sub>R</sub>	reverse current	$V_R = 5 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ; T_j = 25 \text{ °C}$	-	10	-	μA
		$V_R = 10 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$	-	15	60	μA
		$V_R$ = 20 V; $t_p \le 3$ ms; $\delta \le 0.3$ ; $T_j$ = 25 °C	-	30	115	μA
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$V_R = 40 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$	-	325	1250	μA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	75	-	pF
		V <sub>R</sub> = 10 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	22	-	pF
t <sub>rr</sub>	reverse recovery time	$I_F = 0.5 \text{ A}; I_R = 0.5 \text{ A}; I_{R(meas)} = 0.1 \text{ A};$ $T_j = 25 \text{ °C}$	-	3.1	-	ns



pulsed condition

(1) 
$$T_i = 150 \, ^{\circ}C$$

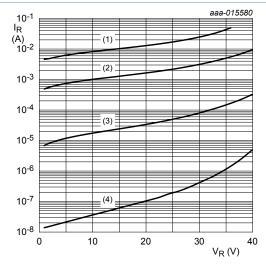
(2) 
$$T_i = 125 \, ^{\circ}C$$

(3) 
$$T_i = 85 \, ^{\circ}C$$

(4) 
$$T_j = 25 \,^{\circ}C$$

(5) T<sub>j</sub> = −40 °C

Fig. 4. Forward current as a function of forward voltage; typical values



pulsed condition

(1) 
$$T_i = 125 \, ^{\circ}C$$

(2) 
$$T_i = 85 \, ^{\circ}C$$

(3) 
$$T_i = 25 \, ^{\circ}C$$

(4) 
$$T_j = -40 \, ^{\circ}\text{C}$$

Fig. 5. Reverse current as a function of reverse voltage; typical values

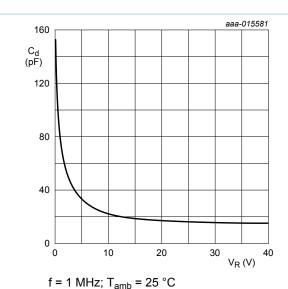
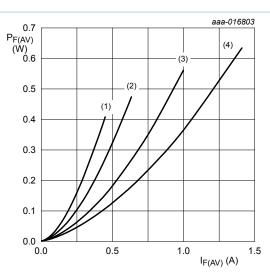


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



 $T_j = 150 \,^{\circ}\text{C}$ 

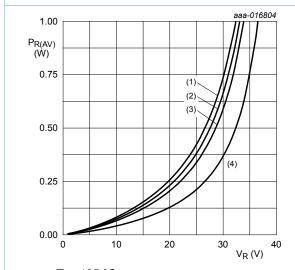
 $(1) \delta = 0.1$ 

(2)  $\delta = 0.2$ 

 $(3) \delta = 0.5$ 

 $(4) \delta = 1$ 

Fig. 7. Average forward power dissipation as a function of average forward current; typical values



T<sub>j</sub> = 125 °C

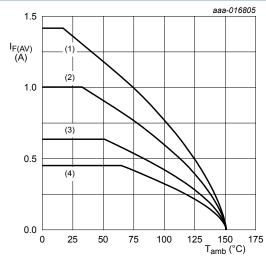
 $(1) \delta = 1$ 

 $(2) \delta = 0.9$ 

 $(3) \delta = 0.8$ 

 $(4) \delta = 0.5$ 

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

T<sub>i</sub> = 150 °C

(1)  $\delta$  = 1; DC

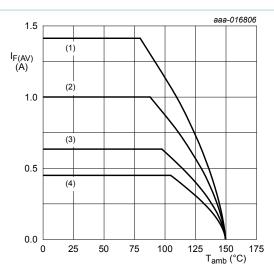
(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta$  = 0.2; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig. 9. Average forward current as a function of ambient temperature; typical values

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FR4 PCB, mounting pad for anode and cathode 1 cm<sup>2</sup> each

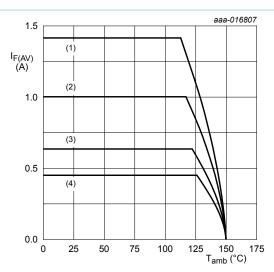
T<sub>i</sub> = 150 °C

(1)  $\delta$  = 1; DC (2)  $\delta$  = 0.5; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta$  = 0.1; f = 20 kHz

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

 $T_i = 150 \,{}^{\circ}\text{C}$ 

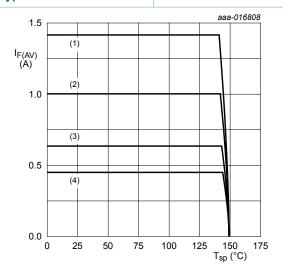
(1)  $\delta = 1$  (DC)

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta$  = 0.1; f = 20 kHz

Fig. 11. Average forward current as a function of ambient temperature; typical values



T<sub>i</sub> = 150 °C

(1)  $\delta$  = 1 (DC)

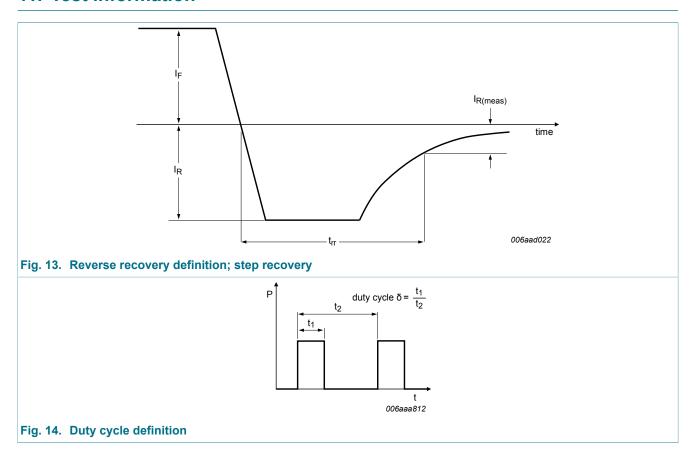
(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

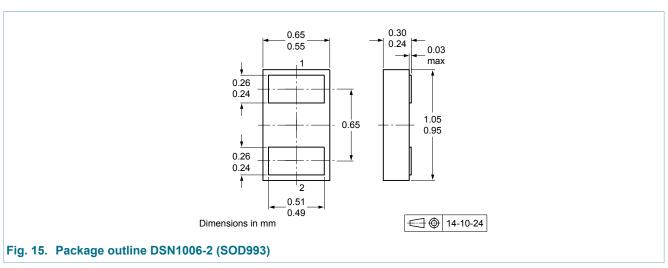
Fig. 12. Average forward current as a function of solder point temperature; typical values

### 11. Test information



The current ratings for the typical waveforms are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

## 12. Package outline

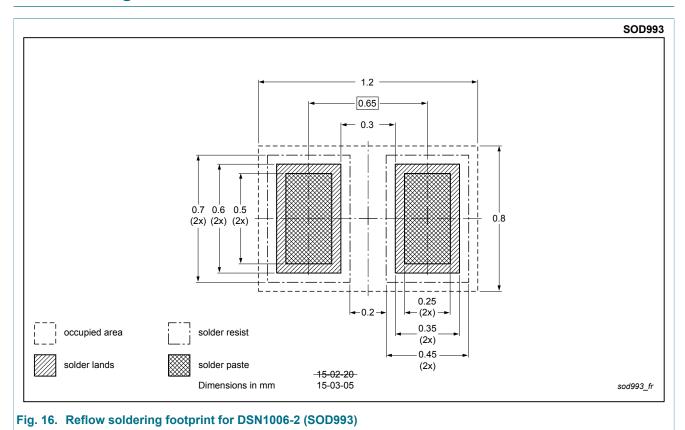


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### 13. Soldering



## 14. Mounting

SOD993 is an ultra small Discretes Silicon No-leads (DSN) package allowing maximized utilization of the package area for active silicon. Due to the special product design, NXP investigated the board assembly process parameters. In order to have an optimum soldering quality, NXP advises following the assembly recommendations explained in AN11689.

# 15. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4010AESB v.3	20151006	Product data sheet	-	PMEG4010AESB v.2
Modifications:	Changed status to "	Product data sheet"		
PMEG4010AESB v.2	20150430	Preliminary data sheet	-	PMEG4010AESB v.1
PMEG4010AESB v.1	20141128	Objective data sheet	-	-

### 16. Legal information

#### 16.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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